

NGTD23T120F2WP

NGTD23T120F2WP Information

Heisener.com

Part Number NGTD23T120F2WP Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

Description IGBT TRENCH FIELD STOP 1200V DIE

Package Die

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









NGTD23T120F2WP Specifications

Manufacturer Part Number	NGTD23T120F2WP
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	Die
Series	-
IGBT Type	Trench Field Stop
Voltage - Collector Emitter Breakdown (Max)	1200V
Current - Collector (Ic) (Max)	-
Current - Collector Pulsed (Icm)	120A
Vce(on) (Max) @ Vge, Ic	2.2V @ 15V, 25A
Power - Max	-
Switching Energy	-
Input Type	Standard
Gate Charge	-
Td (on/off) @ 25°C	-
Test Condition	-
Reverse Recovery Time (trr)	-
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Package / Case	Die
Supplier Device Package	Die
	Report errors?

NGTD23T120F2WP Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

NGTD23T120F2WP Payment Methods



















NGTD23T120F2WP Shipping Methods













If you have any question about NGTD23T120F2WP, please do not hesitate to contact us!

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